

Ripplonic Lamb Shift for Electrons on Liquid Helium

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We study the shift of the energy levels of electrons on a helium surface due to the coupling to the quantum field of surface vibrations. As in quantum electrodynamics, the coupling is known, and it is known to lead to an ultraviolet divergence of the level shifts. We show that there are diverging terms of different nature and use the Bethe-type approach to show that they cancel each other, to leading order. This resolves the long-standing theoretical controversy and explains the existing experiments. The results allow us to study the temperature dependence of the level shift. The predictions are in good agreement with the experimental data, with no adjustable parameters.

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Electrons above the surface of liquid helium were one of the first observed two-dimensional electron systems (2DESs) [1–4]. In this system, the conceptual simplicity is combined with far-from-trivial behavior, which allows studying many-body effects in a well-characterized setting. The system displays the highest mobility known for 2DESs, exceeding $2 \times 10^8 \text{ cm}^2/(\text{Vs})$ [5] and can be exquisitely well controlled [6]. The electron-electron interaction is typically strong, so that the electrons can form a Wigner solid [7,8] or a strongly correlated liquid with unusual transport properties [9,10]. A number of new many-electron phenomena have been found recently [11–15].

An advantageous feature of the system is the simple shape of the confining potential. It is formed by the high Pauli barrier at the helium surface and the image potential. One then expects the electron energy spectrum to be well understood. Indeed, already the first experiment on transitions between the sub-bands of quantized motion normal to the surface showed a good, albeit imperfect, agreement with the model [4]. Much work has been done on improving, sometimes empirically, the form of the confining potential, cf. Refs. [4,16–19]. On the other hand, it has been known that the electrons are also coupled to a bosonic field, the capillary waves on the surface of helium (ripplons), and that this coupling affects the electron energy spectrum [20–24]. The importance of this effect was demonstrated in explaining the Wigner crystallization [8,25] and through cyclotron resonance measurements [26].

In terms of the coupling to a bosonic field, electrons on helium are a condensed-matter analog of systems studied in quantum electrodynamics (QED). In both cases, the spectrum of the bosons and the coupling are known [27], and for electrons on helium the coupling can be controlled. The parallel with QED is further strengthened by the full

quantitative agreement between a large number of experiments on electron transport and the parameter-free theory that accounts for the coupling and also for many-electron effects. This is why the difference between the theoretical and experimental values of the sub-band energy spacing has been a concern. Another significant concern is the well-established experimentally slow energy relaxation of strongly excited electrons. So far, it has been described either phenomenologically or by modifying the form of the electron-ripplon coupling [28].

A major and largely overlooked problem closely related to those mentioned above is the ripplon-induced shift of the energy levels of electron motion normal to the surface. The lowest-order expression is ultraviolet divergent. The divergence is strong, as a high power of the wave number. Unless one deals with it carefully, the resulting level shifts become comparable to the “bare” electron binding energy already for a short-wavelength cutoff approaching twice the interatomic distance. Besides electrons on helium, a similar problem emerges in the analysis of 2D electron systems in semiconductor heterostructures and metal-oxide-semiconductor systems with short-range correlated interface roughness and a high surface barrier. The approach developed below can be extended to such systems as well.

In this Letter, we show that, in fact, the level shift due to the coupling to ripplons is small. The situation is reminiscent of the Lamb shift in QED. In the spirit of the Bethe approach to the analysis of the Lamb shift, we show that, in the electron-ripplon problem, there are two groups of diverging terms, and the leading ultraviolet-divergent terms are compensated in the overall level shift. Interestingly, the remaining correction still displays a power-law ultraviolet divergence, but with a smaller exponent. This shows the nontrivial nature of the compensation. Once account is taken of the natural cutoff at the interatomic distance, the

correction becomes small. It describes a Lamb-shift-type deviation from the energy spectrum in the absence of the electron-riplon coupling.

We also study the temperature-dependent shift of the energy levels. We find a good agreement with the experimental results on the spectra of inter-sub-band transitions [29,30] obtained by studying resonant microwave absorption in a broad range of temperatures and electron densities. The theory also explains the long lifetime of the electron states, which is critical for the potential implementation of a quantum computer based on electrons on helium [31–33]. The proposed divergence compensation mechanism is fairly general for quasi-two-dimensional systems.

The contributions to the level shift due to the warping of the helium surface, i.e., to the ripples, can be separated into three parts. One is kinematic and comes from the electron kinetic energy over a warped surface. Another is electrostatic and comes from the difference of the electron potential energies above the plane and a warped surface. The third comes from the inertia of the surface waves. The key point of the analysis of these contributions is that we have to go beyond the standardly used polaron theory in which the electron system is assumed to be two dimensional. It is necessary to take into account the ripplon-induced mixing of the different states of motion normal to the surface.

The kinematic level shift is the major one. To see how it comes about, we choose $\mathbf{r} = (x, y)$ and $\mathbf{p} = (p_x, p_y)$ as the two-dimensional coordinate and momentum of motion parallel to the surface; the coordinate z is normal to the surface, and the electron motion along z is quantized; see Fig. 1(a). Qualitatively, one can think that the nonuniform surface displacement $\xi(\mathbf{r})$ changes the effective width of the potential well in the z direction. This changes the

kinetic energy of the confined motion. Since $\langle \xi(\mathbf{r}) \rangle = 0$, the change is quadratic in ξ —and in fact, in $\nabla \xi$ —because a uniform surface displacement does not change the energy. The energy change is positive, since the kinetic energy scales as the squared reciprocal confinement length.

On the other hand, the motions parallel and normal to the surface are mixed by the warping. In the second order (again, quadratic in ξ), the mixing leads to shifts of the levels of motion normal to the surface, which are negative for low-lying levels, as expected from the standard perturbation theory. It turns out that, taken separately, both mechanisms display strong ultraviolet divergences of the energy shift, which partly compensate each other.

The warping-induced change of the electrostatic energy has linear and quadratic in $\xi(\mathbf{r})$ terms as well. The shift of the electron energy levels due to the quadratic term also displays an ultraviolet divergence, but it is weaker than for the kinematic mechanism. This is because the image potential is much less sensitive to short-wavelength fluctuations of the helium surface. The divergence is partly compensated by the single-riplon processes, as for the kinematic coupling. The analysis is similar to the analysis of the kinematic effect given below and is provided in the Supplemental Material [34,35].

Our starting point is the electron Hamiltonian for a flat helium surface,

$$H_0 = \hat{T} + V(z), \quad \hat{T} = (2m)^{-1}(\mathbf{p}^2 + p_z^2), \quad (1)$$

where the potential energy $V(z)$ for $z > 0$ comes from the image force and from the electric field E_\perp usually applied to press the electrons to the surface [27,28]. The potential has an atomically steep repulsive barrier at $z = 0$ with height > 1 eV formed by helium atoms. The eigenstates of Hamiltonian (1) are products of the wave functions of quantized motion normal to the surface $|n\rangle \equiv \psi_n(z)$ and the plane waves of lateral motion $\propto \exp(i\mathbf{p}\mathbf{r}/\hbar)$. The energies of the normal and lateral motions are E_n and E_p , and the total energy is $E_{np} = E_n + E_p$.

The ripplon Hamiltonian and the ripplon-induced surface displacement are

$$\hat{H}_r = \hbar \sum_{\mathbf{q}} \omega_{\mathbf{q}} b_{\mathbf{q}}^\dagger b_{\mathbf{q}}, \quad \xi(\mathbf{r}) = \sum_{\mathbf{q}} Q_{\mathbf{q}} e^{i\mathbf{q}\mathbf{r}} (b_{\mathbf{q}} + b_{-\mathbf{q}}^\dagger). \quad (2)$$

Here, $b_{\mathbf{q}}$ is the annihilation operator of a ripplon with the wave number \mathbf{q} and frequency $\omega_{\mathbf{q}}$; $Q_{\mathbf{q}} = (\hbar q / 2\rho\omega_{\mathbf{q}}S)^{1/2}$, where ρ is the helium density and S is the area [36].

The effect of the ripplon-induced curvature of the electron barrier at the helium surface can be taken into account in a standard way [37] by making a canonical transformation $U = \exp[-i\xi(\mathbf{r})p_z/\hbar]$, which shifts the electron z coordinate so that it is counted off from the local position of the surface, $z \rightarrow z - \xi(\mathbf{r})$ [21]. The transformed electron kinetic energy and the ripplon energy

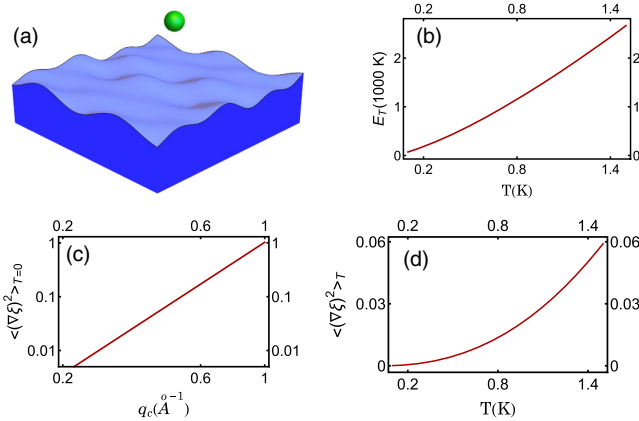


FIG. 1. (a) Sketch of an electron above a warped helium surface. (b) Electron energy $E_T = \hbar^2 q_T^2 / 2m$ for a thermal ripplon wave number q_T , $\hbar \omega_{q_T} = k_B T$. (c) The relative correction to the reciprocal electron mass due to the direct kinematic two-riplon coupling for $T = 0$ as function of the short-wavelength cutoff q_c . (d) Same as in (c), but when only the thermal contribution is taken into account.

$U^\dagger(\hat{T} + \hat{H}_r)U$ is the sum $\hat{T} + \hat{H}_r + \hat{H}_i^{(1)} + \hat{H}_i^{(2)}$, where $\hat{H}_i^{(1)}$ and $\hat{H}_i^{(2)}$ describe the linear and quadratic in $\xi(\mathbf{r})$ kinematic electron-rippion couplings:

$$\begin{aligned}\hat{H}_i^{(1)} &= -\frac{1}{2m}p_z\{\mathbf{p}, \nabla\xi(\mathbf{r})\}_+ + i\hbar^{-1}p_z[\xi(\mathbf{r}), H_r], \\ \hat{H}_i^{(2)} &= p_z^2 h_i^{(2)}, \quad h_i^{(2)} = \frac{1}{2m}(\nabla\xi)^2 + \sum_{\mathbf{q}}\omega_q|Q_q|^2/\hbar,\end{aligned}\quad (3)$$

$$[\{A, B\}_+ = AB + BA, \nabla = (\partial_x, \partial_y)].$$

The term $\hat{H}_i^{(2)}$ averaged over the thermal distribution of ripples gives a correction to the electron energy E_n already in the first order,

$$\Delta E_n^{(2)} = \langle n|p_z^2|n\rangle\langle h_i^{(2)}\rangle. \quad (4)$$

This correction is just a renormalization of the electron mass for motion normal to the surface $m^{-1} \rightarrow m^{-1} + \sum_{\mathbf{q}}|Q_q|^2[2m\omega_q + \hbar q^2(2\bar{n}_q + 1)]/m\hbar$, where $\bar{n}_q = [\exp(\hbar\omega_q/k_B T) - 1]^{-1}$ is the Planck number. Since $\omega_q \propto q^{3/2}$ for large q [38], the sum over \mathbf{q} diverges as $q_c^{7/2}$ for $T = 0$, where q_c is the short-wavelength cutoff. Figure 1(c) shows the factor $\langle(\nabla\xi)^2\rangle$ as a function of the short-wavelength cutoff q_c . If we set $q_c = 1 \text{ \AA}^{-1}$ [39], the energy shift (4) is $\Delta E_n^{(2)} \sim E_n$, indicating the breakdown of the perturbation theory.

Operator $\hat{H}_i^{(1)}$ contributes to the level shift in the second order. For a state with given quantum numbers n and \mathbf{p} , the shift is

$$\Delta E_{n\mathbf{p}}^{(1)} = \sum_{n', \mathbf{q}} \sum_{\alpha=\pm 1} \mathcal{N}_{q\alpha} \frac{|\langle n|p_z|n'\rangle|^2 \Delta_{\mathbf{p}, \mathbf{q}, \alpha}^2}{E_n - E_{n'} - \Delta_{\mathbf{p}, \mathbf{q}, \alpha}}. \quad (5)$$

Here, α allows for the processes with virtual emission ($\alpha = 1$) or absorption ($\alpha = -1$) of a ripplon, $\Delta_{\mathbf{p}, \mathbf{q}, \alpha} = E_{\mathbf{p}+\hbar\mathbf{q}} - E_{\mathbf{p}} + \alpha\hbar\omega_q$ is the difference of the energies of the in-plane motion in the initial and intermediate electron states with the added or subtracted ripplon energy, and $\mathcal{N}_{q\alpha} = |Q_q|^2[\bar{n}_q + (1 + \alpha)/2]/\hbar^2$.

We find the overall kinematic energy shift $\Delta E_{n\mathbf{p}}^{\text{kin}} = \Delta E_{n\mathbf{p}}^{(1)} + \Delta E_n^{(2)}$ by rewriting in Eq. (5)

$$\frac{\Delta_{\mathbf{p}, \mathbf{q}, \alpha}}{E_n - E_{n'} - \Delta_{\mathbf{p}, \mathbf{q}, \alpha}} = \frac{E_n - E_{n'}}{E_n - E_{n'} - \Delta_{\mathbf{p}, \mathbf{q}, \alpha}} - 1. \quad (6)$$

The last term here exactly cancels $\Delta E_n^{(2)}$ in $\Delta E_{n\mathbf{p}}^{\text{kin}}$, since $\sum_{n'} |\langle n|p_z|n'\rangle|^2 = \langle n|p_z^2|n\rangle$ and Q_q, ω_q are independent of the direction of \mathbf{q} . Then

$$\Delta E_{n\mathbf{p}}^{\text{kin}} = \sum_{n', \mathbf{q}, \alpha} \mathcal{N}_{q\alpha} \frac{\Delta_{\mathbf{p}, \mathbf{q}, \alpha} |\langle n|p_z|n'\rangle|^2 (E_n - E_{n'})}{E_n - E_{n'} - \Delta_{\mathbf{p}, \mathbf{q}, \alpha}}. \quad (7)$$

We will be interested in $\Delta E_{n\mathbf{p}}^{\text{kin}}$ for low-lying out-of-plane states, $n \sim 1$, and for small momenta $p \lesssim (mk_B T)^{1/2}$.

The unperturbed energies $E_n, E_{n'}$ and the matrix elements $\langle n'|p_z|n\rangle$ in Eq. (7) can be found from the one-dimensional Schrödinger equation for an electron above the flat helium surface. To get an analytic insight, we note that the main contribution to Eq. (7) comes from large in-plane wave numbers q compared to the reciprocal out-of-plane localization length r_B^{-1} in the ground state $n = 1$ ($r_B \lesssim 100 \text{ \AA}$ [36,40]). The energy $\Delta_{\mathbf{p}, \mathbf{q}, \alpha}$ largely exceeds $k_B T$ and $|E_n|$ with $n \sim 1$. Then, of primary importance is the contribution to Eq. (7) of highly excited states with $n' \gg 1$. Such states are semiclassical. They correspond to electron motion in an almost triangular potential well formed by the barrier at $z = 0$ and the field eE_\perp that presses the electrons against the surface. The Wentzel-Kramers-Brillouin (WKB) approximation gives $E_{n'} \approx [3\pi\hbar eE_\perp(n' - 1/4)/2\sqrt{2m}]^{2/3}$ for $n' \gg 1$ (a better approximation is based on matching the WKB and the small- z wave functions [35]). Since the large- n' wave functions are fast oscillating on length r_B , one can show that $|\langle n'|p_z|n\rangle|^2 \approx (\hbar^4 eE_\perp/2mE_{n'})|\partial_z \psi_n|_{z=0}^2$.

Changing from summation over n' in Eq. (7) to integration, we obtain from the above estimate

$$\Delta E_{n\mathbf{p}}^{\text{kin}} \approx \frac{\hbar}{\sqrt{2m}} |\partial_z \psi_n|_{z=0}^2 \sum_{\mathbf{q}} |Q_q|^2 (2\bar{n}_q + 1) \Delta_{\mathbf{p}, \mathbf{q}, 1}^{1/2}. \quad (8)$$

We disregarded here the contribution of the states with energies $E_{n'} \lesssim E_n$. We also disregarded the ripplon energy $\hbar\omega_q$ compared to the in-plane electron energy $E_{\hbar\mathbf{q}}$. This is a good approximation, because ripples are slow, $\omega_q \approx (\sigma/\rho)^{1/2} q^{3/2}$, where σ is the helium surface tension. Therefore, their thermal momentum q_T given by condition $\hbar\omega_{q_T} = k_B T$ corresponds to the electron energy $E_{\hbar q_T}$ varying from $\approx 73 \text{ K}$ to $\approx 1.6 \times 10^3 \text{ K}$ for T varying from 0.1 to 1 K; see Fig. 1(b).

The $T = 0$ term in Eq. (8) still has an ultraviolet divergence. It scales with the short-wavelength cutoff q_c as $q_c^{5/2}$. This is a much weaker divergence than that of $\Delta E_n^{(2)}$. Overall, the $T = 0$ term is $\sim \Delta E_n^{(2)}/(q_c r_B)$. For the cutoff $q_c \sim 1 \text{ \AA}^{-1}$, this term is on the order of a few percent of the electron binding energy $|E_1| = \hbar^2/2mr_B^2 \sim 8 \text{ K}$. Its dependence on the control parameter E_\perp is described by Eq. (7). There are also other contributions to the $T = 0$ level shift. They include the effect of the electron correlations [11,41], the intraband polaronic shift [22], and, last but not least, the finite steepness and height of the barrier for electron penetration into the liquid helium [4,16–19]. It is important that, as it follows from the previous work and

from Eq. (8), all contributions to the $T = 0$ level shift are small.

Understanding the experiment requires finding the T -dependent part of the shift of the electron energy levels. For $T \gtrsim 10$ mK, the kinematic contribution (7) is the dominating part of this shift. From Fig. 1(d), this shift is small even before the renormalization. However, it is directly observable. In the approximation (8), the T -dependent part $\Delta E_{npT}^{\text{kin}}$ of the kinematic level shift is

$$\Delta E_{npT}^{\text{kin}} \approx A_n^{\text{kin}} (k_B T)^{5/3}. \quad (9)$$

The coefficient $A_n^{\text{kin}} \approx c^{\text{kin}} |\partial_z \psi_n|_{z=0}^2 (\hbar^4 \rho / \sigma^4)^{1/3} / m$ [$c^{\text{kin}} = \Gamma(5/3)\zeta(5/3) \approx 0.1$] sensitively depends on the electron state n . Equation (9) predicts a power-law dependence of the level shift on T with exponent $5/3$.

The dependence of the energy renormalization on the level number n leads to a temperature-dependent shift of the peaks of microwave absorption due to $n \rightarrow n'$ transitions. Since the characteristic ripplon momenta $\hbar q$ in Eq. (7) largely exceed the thermal electron momentum, the level shift is essentially independent of the electron momentum \mathbf{p} .

In Fig. 2, we present the results for the thermally induced shift $\Delta\omega_{21}$ of the transition frequency $\omega_{21} = (E_2 - E_1)/\hbar$. It is calculated as a sum of the kinematic contribution (7) and the contribution from the electrostatic coupling given in the SM, keeping only the T -dependent terms in both expressions. To compare the theory with the experiment, the experimentally measured transition frequency [30] was extrapolated to $T = 0$, and the shift was counted off from the extrapolated value. The calculated T -dependent frequency shift is free from the ambiguity related to the form of the electron potential at the atomic distance from the helium surface.

The theoretical curve in Fig. 2 is in excellent agreement with the experimental data shown by squares, with no

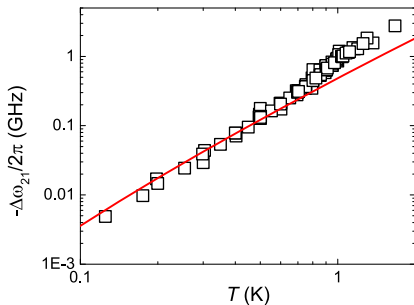


FIG. 2. Temperature dependence of the $1 \rightarrow 2$ transition frequency calculated for $E_{\perp} = 106$ V/cm (solid line). The squares are the experimental results [30]. In the studied density range 0.67×10^7 – 2.4×10^7 cm $^{-2}$, no dependence on the electron density was found, and the data for different densities are combined.

adjustable parameters. A deviation is observed only for $T \gtrsim 1$ K, where scattering by helium vapor atoms becomes substantial. The simple expression (9) gives $\Delta\omega_{21}$, which differs from the numerical result by a factor ~ 3 .

Two-riplon coupling has been attracting much interest as a mechanism of electron energy relaxation [28,32,42–44]. Its importance is a consequence of the slowness of ripples, which makes single-riplon scattering essentially elastic. In contrast, for two-riplon scattering, the total wave number of the participating ripples $|\mathbf{q}_1 + \mathbf{q}_2|$ can be of the order of the reciprocal electron thermal wavelength or the reciprocal magnetic length, whereas the wave number of each ripplon $q_{1,2}$ can be much larger, so that the ripplon energies $\hbar\omega_{q_1} \approx \hbar\omega_{q_2}$ can be comparable to $k_B T$, the inter-sub-band energy gap $|E_n - E_{n'}|$, or the Landau level spacing.

From Eq. (3), the matrix element of an electron transition $|n, \mathbf{p}\rangle \rightarrow |n', \mathbf{p}'\rangle$ calculated for the direct kinematic two-riplon coupling $\hat{H}_i^{(2)}$ is $\propto q_1 q_2 \approx -q_1^2$. It implies a high rate of deeply inelastic electron relaxation for large $q_{1,2}$. The single-electron kinematic coupling to ripples $\hat{H}_i^{(1)}$ very strongly reduces the scattering rate. An approach similar to that used in the analysis of the level shifts allows one to show that the term $\propto q_1 q_2$ drops out from the transition matrix element calculated to the second order in $\hat{H}_i^{(1)}$. A similar cancellation occurs for the electrostatic electron-riplon coupling [35]. This strongly reduces the energy relaxation rate, bringing it within the realm of the experiment. The full analysis of the electron energy relaxation requires also taking into account scattering by phonons in helium [32]. This analysis is beyond the scope of the present Letter.

In conclusion, we have shown that the system of electrons coupled to the quantum field of capillary waves on the helium surface enables studying a condensed-matter analog of the Lamb shift, which in this case is the shift of the sub-bands of the quantized motion transverse to the surface. As in the case of the Lamb shift, the matrix elements of the electron coupling to the quantum field are known, and there are terms in the expression for the shift that display an ultraviolet divergence. We have shown that the analysis may not be limited to the conventional intra-sub-band processes. We have revealed the diverging inter-sub-band terms and used the Bethe trick from the Lamb shift theory to demonstrate that different diverging terms cancel each other to the leading order, making the overall shift small. The considered system makes it possible to study the dependence of the level shift on temperature. Our theoretical results are in excellent agreement with the experimental observations.

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- [1] R. Williams, R. S. Crandall, and A. H. Willis, *Phys. Rev. Lett.* **26**, 7 (1971).
 - [2] W. T. Sommer and D. J. Tanner, *Phys. Rev. Lett.* **27**, 1345 (1971).
 - [3] T. R. Brown and C. C. Grimes, *Phys. Rev. Lett.* **29**, 1233 (1972).
 - [4] C. C. Grimes, T. R. Brown, M. L. Burns, and C. L. Zipfel, *Phys. Rev. B* **13**, 140 (1976).
 - [5] K. Shirahama, S. Ito, H. Suto, and K. Kono, *J. Low Temp. Phys.* **101**, 439 (1995).
 - [6] F. R. Bradbury, M. Takita, T. M. Gurrieri, K. J. Wilkel, K. Eng, M. S. Carroll, and S. A. Lyon, *Phys. Rev. Lett.* **107**, 266803 (2011).
 - [7] C. C. Grimes and G. Adams, *Phys. Rev. Lett.* **42**, 795 (1979).
 - [8] D. S. Fisher, B. I. Halperin, and P. M. Platzman, *Phys. Rev. Lett.* **42**, 798 (1979).
 - [9] M. I. Dykman and L. S. Khazan, *Sov. Phys. JETP* **50**, 747 (1979).
 - [10] M. I. Dykman, M. J. Lea, P. Fozooni, and J. Frost, *Phys. Rev. Lett.* **70**, 3975 (1993).
 - [11] D. Konstantinov, M. I. Dykman, M. J. Lea, Y. Monarkha, and K. Kono, *Phys. Rev. Lett.* **103**, 096801 (2009).
 - [12] H. Ikegami, H. Akimoto, D. G. Rees, and K. Kono, *Phys. Rev. Lett.* **109**, 236802 (2012).
 - [13] D. Konstantinov, A. Chepelianskii, and K. Kono, *J. Phys. Soc. Jpn.* **81**, 093601 (2012).
 - [14] A. D. Chepelianskii, M. Watanabe, K. Nasyedkin, K. Kono, and D. Konstantinov, *Nat. Commun.* **6**, 7210 (2015).
 - [15] D. G. Rees, N. R. Beysengulov, J.-J. Lin, and K. Kono, *Phys. Rev. Lett.* **116**, 206801 (2016).
 - [16] F. Stern, *Phys. Rev. B* **17**, 5009 (1978).
 - [17] M. V. Rama Krishna and K. B. Whaley, *Phys. Rev. B* **38**, 11839 (1988).
 - [18] E. Cheng, M. W. Cole, and M. H. Cohen, *Phys. Rev. B* **50**, 1136 (1994).
 - [19] M. H. Degani, G. A. Farias, and F. M. Peeters, *Phys. Rev. B* **72**, 125408 (2005).
 - [20] V. B. Shikin, *Sov. Phys. JETP* **33**, 387 (1971).
 - [21] V. Shikin and Y. Monarkha, *J. Low Temp. Phys.* **16**, 193 (1974).
 - [22] S. A. Jackson and P. M. Platzman, *Phys. Rev. B* **24**, 499 (1981).
 - [23] S. A. Jackson and P. M. Platzman, *Phys. Rev. B* **25**, 4886 (1982).
 - [24] S. N. Klimin, J. Tempere, V. R. Misko, and M. Wouters, *Eur. Phys. J. B* **89**, 172 (2016).
 - [25] S. Yücel, L. Menna, and E. Y. Andrei, *Phys. Rev. B* **47**, 12672 (1993).
 - [26] L. Wilen and R. Giannetta, *Phys. Rev. Lett.* **60**, 231 (1988).
 - [27] *Two-Dimensional Electron Systems on Helium and Other Cryogenic Surfaces*, edited by E. Andrei (Kluwer Academic, Dordrecht, 1997).
 - [28] Y. Monarkha and K. Kono, *Two-Dimensional Coulomb Liquids and Solids* (Springer, Berlin, 2004).
 - [29] E. Collin, W. Bailey, P. Fozooni, P. G. Frayne, P. Glasson, K. Harrabi, M. J. Lea, and G. Papageorgiou, *Phys. Rev. Lett.* **89**, 245301 (2002).
 - [30] E. Collin, W. Bailey, P. Fozooni, P. G. Frayne, P. Glasson, K. Harrabi, and M. J. Lea, *arXiv:1707.02119*.
 - [31] P. M. Platzman and M. I. Dykman, *Science* **284**, 1967 (1999).
 - [32] M. I. Dykman, P. M. Platzman, and P. Sedighrad, *Phys. Rev. B* **67**, 155402 (2003).
 - [33] D. I. Schuster, A. Fragner, M. I. Dykman, S. A. Lyon, and R. J. Schoelkopf, *Phys. Rev. Lett.* **105**, 040503 (2010).
 - [34] See Supplemental Material at <http://link.aps.org/supplemental/10.1103/PhysRevLett.119.256802> for the details of the numerical calculations of the relevant matrix elements and the semiclassical approximation for highly excited states.
 - [35] The two-rippion processes due to the electrostatic electron-rippion coupling are discussed in the Supplemental Material [34].
 - [36] M. W. Cole, *Rev. Mod. Phys.* **46**, 451 (1974).
 - [37] A. B. Migdal, *Qualitative Methods in Quantum Theory* (Westview Press, New York, 2000).
 - [38] L. D. Landau and E. M. Lifshitz, *Fluid Mechanics*, 2nd ed. (Elsevier, Oxford, 1987).
 - [39] Such a cutoff corresponds to the estimate [K. R. Atkins, *Can. J. Phys.* **31**, 1165 (1953)] that $q_c^2/4\pi$ is the number of helium atoms in the surface monolayer. Ripples with $q \lesssim 1.5 \text{ \AA}^{-1}$ were seen in the neutron scattering spectra by H. J. Lauter, H. Godfrin, V. L. P. Frank, and P. Leiderer, *Phys. Rev. Lett.* **68**, 2484 (1992).
 - [40] M. W. Cole, *Phys. Rev. B* **2**, 4239 (1970).
 - [41] D. K. Lambert and P. L. Richards, *Phys. Rev. Lett.* **44**, 1427 (1980).
 - [42] M. I. Dykman, *Phys. Status Solidi B* **88**, 463 (1978).
 - [43] Y. P. Monarkha, *Fiz. Nizk. Temp.* **4**, 1093 (1978).
 - [44] Y. P. Monarkha, S. S. Sokolov, A. V. Smorodin, and N. Studart, *Low Temp. Phys.* **36**, 565 (2010).

Supplemental Material: Ripplonic Lamb Shift for Electrons on Liquid Helium

The Supplemental Material describes the technical details of the calculations carried out in the main text.

I. THE WKB WAVE FUNCTIONS

In this section we describe the analytical approximation for the energies E_n and the eigenfunctions $\psi_n(z)$ of highly excited states of motion normal to the helium surface. For energies $\lesssim 1$ eV and for the distances from the surface $z \gtrsim 1\text{\AA}$, the confining potential above the flat helium surface in Eq. (??) has the form

$$V(z) = -\Lambda z^{-1} + eE_{\perp}z, \quad \Lambda = e^2 \frac{\epsilon - 1}{4(\epsilon + 1)}, \quad (1)$$

where ϵ is the helium dielectric constant, whereas $V(z) \rightarrow \infty$ for $z \rightarrow -0$. We note that the effect of the ripples on the shift of the electron energy levels is accounted for directly, therefore it would be inconsistent to consider the smearing of the helium surface due to the ripples. However, Eq. (1) has to be modified on the atomic scale, which contributes to the $T = 0$ shift of the electron energy levels [1–5], as indicated in the main text.

We change to dimensionless length, energy, and pressing field,

$$\zeta = z/r_B, \quad \varepsilon_n = E_n/R, \quad F = (eE_{\perp}r_B)/R, \quad (2)$$

($r_B = \hbar^2/\Lambda m$ and $R = \hbar^2/2mr_B^2$ are the localization length of the ground state and the electron binding energy for $E_{\perp} = 0$). We will assume that the dimensionless force is small, $F \lesssim 1$; in the experiment discussed in this paper $F \sim 0.1$.

In the variables (2) the Schrödinger equation for the motion normal to the surface becomes

$$\left[-\frac{d^2}{d\zeta^2} - \frac{2}{\zeta} + F\zeta \right] \psi_n(\zeta) = \varepsilon_n \psi_n(\zeta) \quad (3)$$

with the boundary condition $\psi_n(0) = 0$.

For large energies $\varepsilon_n \gg 1$ and not too small ζ the solution can be sought in the WKB form

$$\begin{aligned} \psi_n(\zeta) &= \frac{C_n}{\sqrt{p(\zeta, \varepsilon_n)}} \sin \left[S(\varepsilon_n) - \int_0^{\zeta} p(\zeta', \varepsilon_n) d\zeta' + \frac{\pi}{4} \right], \\ S(\varepsilon_n) &= \int_0^{\zeta_n} p(\zeta', \varepsilon_n) d\zeta', \end{aligned} \quad (4)$$

where $p(\zeta, \varepsilon) = [\varepsilon + 2/\zeta - F\zeta]^{1/2}$ is the scaled classical momentum of motion in the z -direction and C_n is the normalization constant, which we set to be a real number. The value of ζ_n is given by equation $p(\zeta_n, \varepsilon_n) = 0$; for large ε_n we have $\zeta_n \approx F^{-1}\varepsilon_n + 2\varepsilon_n^{-1} \gg 1$.

The WKB approximation breaks down for small ζ , because the confining potential is singular at $\zeta \rightarrow 0$. For the WKB to apply, the de Broglie wavelength should be small compared to the distance on which it changes. This means that Eq. (4) applies for $\zeta \gg \varepsilon_n^{-3/4}$.

For small ζ , where $F\zeta \ll \varepsilon + 2/\zeta$, we can disregard the term $F\zeta$ in Eq. (3). The solution of this equation then becomes

$$\psi_n(\zeta) = \tilde{C}_n \zeta e^{-i\varepsilon_n^{1/2}\zeta} {}_1F_1 \left(i\varepsilon_n^{-1/2} + 1, 2, 2i\varepsilon_n^{1/2}\zeta \right) + \text{c.c.}, \quad (5)$$

where ${}_1F_1$ is the confluent hypergeometric function and \tilde{C}_n is a constant. We will see that \tilde{C}_n can be assumed real, in which case the term $\propto {}_1F_1$ and its complex conjugate are equal.

The solutions (4) and (5) should match in the range where $\varepsilon_n^{3/4}\zeta \gg 1$ and at the same time $F\zeta \ll \varepsilon_n + 2/\zeta$. In the considered case of large ε_n , both solutions should apply in the range $\varepsilon_n/F \gg \zeta \gg \varepsilon_n^{-1/2}$. For $\varepsilon_n^{1/2}\zeta \gg 1$ we have

$$\begin{aligned} {}_1F_1 \left(i\varepsilon_n^{-1/2} + 1, 2, 2i\varepsilon_n^{1/2}\zeta \right) &\approx [1/\Gamma(1 + i\varepsilon_n^{-1/2})] \\ &\times \exp[2i\varepsilon_n^{1/2}\zeta + (i\varepsilon_n^{-1/2} - 1) \log(2i\varepsilon_n^{1/2}\zeta)], \end{aligned}$$

so that, assuming \tilde{C}_n to be real, we have in this range from Eq. (5)

$$\begin{aligned} \psi_n(\zeta) &\approx \tilde{C}_n \varepsilon_n^{-1/2} e^{-\pi/2\varepsilon_n^{1/2}} \\ &\times \sin \left\{ \varepsilon_n^{1/2}\zeta + \varepsilon_n^{-1/2} [\ln(2\varepsilon_n^{1/2}\zeta) + \gamma] \right\}, \end{aligned} \quad (6)$$

(γ is the Euler constant), whereas Eq. (4) gives

$$\begin{aligned} \psi_n(\zeta) &\approx C_n \varepsilon_n^{-1/4} \sin \left\{ S(\varepsilon_n) + \frac{\pi}{4} - \varepsilon_n^{1/2}\zeta \right. \\ &\left. - \varepsilon_n^{-1/2} [1 + \ln(2\varepsilon_n\zeta)] \right\} \end{aligned} \quad (7)$$

By comparing Eqs. (6) and (7), we obtain

$$S(\varepsilon_n) = \pi \left(n - \frac{1}{4} \right) + \varepsilon_n^{-1/2} (1 - \gamma + \ln \varepsilon_n^{1/2}) \quad (8)$$

with integer n ; $\tilde{C}_n = (-1)^{n+1} C_n \varepsilon_n^{1/4} \exp(\pi/2\varepsilon_n^{1/2})$.

The classical action $S(\varepsilon)$ can be found for small F/ε^2 and $\varepsilon \gg 1$, where the image potential can be considered a perturbation. The image-potential induced correction is nonanalytic in ε ,

$$S(\varepsilon) \approx \frac{2\varepsilon^{3/2}}{3F} + \varepsilon^{-1/2} \log(c_\varepsilon \varepsilon^2/F), \quad F/\varepsilon^2 \ll 1, \quad (9)$$

where constant $c_\varepsilon \approx 20$ is estimated by interpolating the numerical value of $S(\varepsilon)$. Equations (8) and (9) give the

energy spectrum of the excited states with logarithmic corrections from the image potential, $\varepsilon_n \approx \varepsilon_n^{(0)} + \varepsilon_n^{(1)}$,

$$\begin{aligned}\varepsilon_n^{(0)} &= [(3\pi F/2)(n-1/4)]^{2/3}, \\ \varepsilon_n^{(1)} &= -\frac{F}{\varepsilon_n^{(0)}} \left[\frac{3}{2} \ln \varepsilon_n^{(0)} - 1 + \gamma + \ln(c_\varepsilon/F) \right].\end{aligned}\quad (10)$$

To the leading order in ε_n^{-1} , the normalization constant C_n can be calculated disregarding the image potential. From Eq. (4), $C_n \approx F^{1/2} \varepsilon_n^{-1/4}$.

For very large ε_n one can disregard the image potential in Eq. (3) and assume that the electrons are in a triangular well. The solution $\psi_n(\zeta)$ can be sought in terms of the Airy functions as $\text{Ai}(F^{1/3}(\zeta - F^{-1}\varepsilon_n))$, with ε_n determined by the condition $\psi_n(0) = 0$. This gives asymptotically the same leading term $\varepsilon_n^{(0)}$ in the expression for the energy, ε_n . The correction from the image potential can be calculated as $-2\langle\psi_n|\zeta^{-1}|\psi_n\rangle$; the result is close to Eq. (10) for $\varepsilon_n^{(1)}$.

In order to compare the results with the experiment [6, 7], we performed a detailed numerical study of the energies and the wave functions for the field $E_\perp = 106$ V/cm used in the experiment. We calculated the energies E_n as well as the matrix elements of the momentum p_z (and of the electrostatic interaction, see below) for $n \leq 30$ by numerically solving the Schrödinger equation (3). For larger n , one can use Eq. (5) to describe the wave functions in the region of small $\zeta \lesssim 1$, which contribute to the overlap integrals $\langle n|p_z|n_1\rangle$ with $n_1 \sim 1$. Expression (5) for ψ_n was corrected by multiplying it by an extra factor $\exp(iF\zeta^2/4\varepsilon_n^{1/2})$. This factor accounts for the field-induced term in the WKB expression (4), which was dropped in Eq. (7) to match Eq. (5), which refers to the limit $F\zeta^2 \rightarrow 0$.

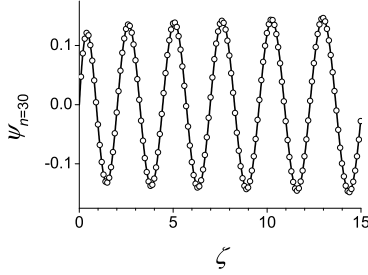


FIG. 1. Solid line: the analytical expression (5) for the wave function of the level $n = 30$ at small distance from the surface; the expression has been corrected by the WKB factor $\exp(iF\zeta^2/4\varepsilon_n^{1/2})$. The numerical results are shown by dots. The data refers to $E_\perp = 106$ V/cm, the dimensionless energy of the level is $\varepsilon_{30} = 6.57$

We found that for $n \gtrsim 20$ functions $\psi_n(\zeta)$ modified this way are in a very good agreement with the numerically calculated wave functions in the whole region $\zeta \ll \varepsilon_n/F$, see Fig.1. The values of the matrix elements $\langle n|p_z|n_1\rangle$ calculated with such $\psi_n(\zeta)$ for $n_1 = 1, 2$ are in a very

TABLE I. Values of the scaled matrix elements $\pi_{1n} = (i/\hbar)r_B\langle n|p_z|1\rangle$ and $\pi_{2n} = (i/\hbar)r_B\langle n|p_z|2\rangle$ calculated for $E_\perp = 106$ V/cm and for large n using Eq. (5) with the WKB correcting factor (see Fig. 1) and the approximation of a triangular potential well. The wave functions $\psi_{1,2}$ are calculated numerically. For comparison, the numerical solutions of Eq. (3) for $n = 30$ give $\pi_{1n} = 0.0662$ and $\pi_{2n} = 0.0415$.

n	Equation (3)		Triangular well	
	π_{1n}	$[\pi_{2n}]$	π_{1n}	$[\pi_{2n}]$
30	0.0663	[0.0415]	0.0740	[0.0443]
10^2	0.0347	[0.0199]	0.0419	[0.0239]
10^3	0.0091	[0.0049]	0.0104	[0.0056]
10^4	0.0021	[0.0011]	0.0023	[0.0012]
10^5	0.0005	[0.0003]	0.0005	[0.0003]

good agreement with the numerical values, too, see Table I. Therefore in the numerical calculations for large n we used these functions. The matrix elements $\langle n|p_z|n_1\rangle$ become close to those for ψ_n calculated in the triangular well approximation for $n \gtrsim 10^4$.

As a test of the accuracy of our numerical calculation we checked the convergence of the sums

$$\begin{aligned}\sum_{n' \leq n_{\max}} |\langle n'|p_z|n\rangle|^2 &\rightarrow \langle n|p_z^2|n\rangle, \quad n_{\max} \rightarrow \infty, \\ \sum_{n' \leq n_{\max}, E_{n'} \neq E_n} \frac{|\langle n'|p_z|n\rangle|^2}{(E_n - E_{n'})} &\rightarrow -m/2, \quad n_{\max} \rightarrow \infty.\end{aligned}\quad (11)$$

The results presented in Fig. 2 show slow, but consistent convergence.

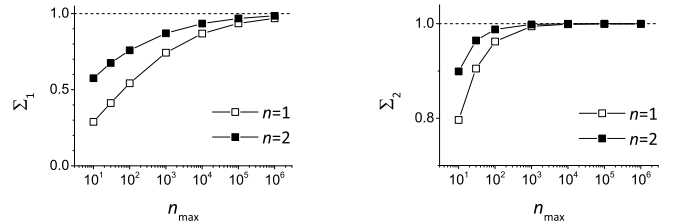


FIG. 2. The convergence of the numerically evaluated sums (11) relevant for finding the energy shift of the states $n = 1$ and $n = 2$; $\Sigma_1 = \sum_{n' \leq n_{\max}} |\langle n'|p_z|n\rangle|^2 / \langle n|p_z^2|n\rangle$ and $\Sigma_2 = (2/m) \sum_{n' \leq n_{\max}} |\langle n'|p_z|n\rangle|^2 / (E_{n'} - E_n)$. The data refer to the pressing field $E_\perp = 106$ V/cm used in the experiment.

As expected from the estimate that led to Eq. (8) of the main text, the matrix elements $\langle n|p_z|n_1\rangle$ fall off approximately as $n^{-2/3}$ for $n \gg 1$ and $n_1 \sim 1$. Therefore it was necessary to sum over a large number of the virtual states in Eq. (7) of the main text. In this equation the summation index is n' , and in Eq. (11) and below we refer to sums over n' for given n . If the sum over n' in Eq. (7)

of the main text is limited to $n' \leq 10^5$, the energy $E_{n'}$ is ≤ 0.98 eV for the considered $E_\perp = 106$ V/cm, which is on the boundary of the approximation of an infinite potential barrier at the helium surface.

The shape of the electron barrier $V(z)$ on the helium surface for energies > 1 eV and the form of the electron wave functions for the states with energies > 1 eV are not known. Also, the shape of the wave function of the low lying states at distances $< 1\text{\AA}$ from the surface is not known either. However, we can find the contribution of the highly excited states to the level shift using the sum rules (11).

To see how it comes about we note first that, in the T -dependent term in Eq. (7) of the main text for the level shift, the sum over the ripplon wave vectors \mathbf{q} is limited to $q \lesssim q_T$. Therefore, for temperatures $T \lesssim 0.8$ K, as seen from Fig. 1(b) of the main text, $\Delta_{\mathbf{p},\mathbf{q},\alpha} < 0.1$ eV. If $E_{n_{\max}} - E_n \gg \Delta_{\mathbf{p},\mathbf{q},\alpha}$, in the terms with $n' > n_{\max}$ in Eq. (7) of the main text one can expand the denominator in $\Delta_{\mathbf{p},\mathbf{q},\alpha}/(E_n - E_{n'})$. The sums over $n' > n_{\max}$ for the terms of the zeroth and first order are then given by the above sum rules with the subtracted terms for $n' < n_{\max}$. Therefore, once the summation in Eq. (7) of the main text has been done for $n < n_{\max}$, the overall level shift is known from the sum rules to the first order in the parameter $\delta_{\max} = \Delta_{\mathbf{p},q_T,\alpha}/(E_{n_{\max}} - E_n)$ irrespective of the form of the barrier $V(z)$. The second-order term in δ_{\max} can be easily found also using the sum rule for $|\langle n|p_z|n'\rangle|^2/(E_n - E_{n'})^2$.

For $E_\perp = 106$ V/cm and $n_{\max} = 10^5$, we have $\delta_{\max} \sim 0.1$. Given that the sum rules hold very well for the wave functions we have found, we could therefore extend the summation in Eq. (7) to $n' \rightarrow \infty$ using these wave functions. This is the procedure used to obtain the energy shift in Fig. 2 of the main text.

II. CONTRIBUTION OF THE ELECTROSTATIC COUPLING

Ripplon-induced warping of the helium surface leads to a change of the electron image potential. The energy of the electron-ripplon coupling is the change of the polarization energy of liquid helium in the electric field of the electron. For the electron located at \mathbf{r} it has the form [8, 9]

$$V^{\text{pol}}(\mathbf{r}, z) = -\frac{\Lambda}{\pi} \int d\mathbf{r}_1 \int_0^{\xi(\mathbf{r}_1) - \xi(\mathbf{r})} dz_1 \times [(\mathbf{r} - \mathbf{r}_1)^2 + (z - z_1)^2]^{-2}, \quad (12)$$

where $\Lambda = e^2(\epsilon_{\text{He}} - 1)/8$ ($\epsilon_{\text{He}} \approx 1.057$ is the helium dielectric constant and we disregard the terms of higher order in $\epsilon_{\text{He}} - 1$).

Because the ratio $\langle \xi^2 \rangle^{1/2}/r_B$ is small, one can expand the energy (12) to the second order in $\xi(\mathbf{r})$. One should also take into account another part of the electrostatic

energy, which is the energy of the electron in the transverse field E_\perp . This energy changes when the electron position is shifted by $\xi(\mathbf{r})$. The expression for the total electrostatic part of the electron-ripplon coupling energy then reads

$$\hat{H}_i^{\text{el}} = \sum_{\mathbf{q}} V_{\mathbf{q}}^{(1)}(z) \xi_{\mathbf{q}} e^{i\mathbf{q}\mathbf{r}} + \sum_{\mathbf{q}_1, \mathbf{q}_2} V_{\mathbf{q}_1, \mathbf{q}_2}^{(2)}(z) \xi_{\mathbf{q}_1} \xi_{\mathbf{q}_2} e^{i(\mathbf{q}_1 + \mathbf{q}_2)\mathbf{r}}. \quad (13)$$

Here, $\xi_{\mathbf{q}} = Q_q(b_{\mathbf{q}} + b_{-\mathbf{q}}^\dagger)$, see Eq. (2) of the main text. Functions $V_{\mathbf{q}}^{(1)}$ and $V_{\mathbf{q}_1, \mathbf{q}_2}^{(2)}$ describe one- and two-ripplon coupling, respectively. They are given in Refs. 8–10,

$$V_{\mathbf{q}}^{(1)}(z) = \Lambda z^{-2} [1 - qz K_1(qz)] + eE_\perp, \\ V_{\mathbf{q}_1, \mathbf{q}_2}^{(2)}(z) = -\frac{\Lambda}{z^3} + \frac{\Lambda}{2z} [q_1^2 K_2(q_1 z) + q_2^2 K_2(q_2 z) - (\mathbf{q}_1 + \mathbf{q}_2)^2 K_2(|\mathbf{q}_1 + \mathbf{q}_2|z)] \quad (14)$$

$K_{1,2}(x)$ are the modified Bessel functions. In the last term in Eq. (14) for $V_{\mathbf{q}_1, \mathbf{q}_2}^{(2)}$ one should replace $(\mathbf{q}_1 + \mathbf{q}_2)^2 K_2(|\mathbf{q}_1 + \mathbf{q}_2|z)$ with $2/z^2$ for $\mathbf{q}_1 = -\mathbf{q}_2$.

The expansion of $V^{\text{pol}}(\mathbf{r}, z)$ in $\xi(\mathbf{r})$ breaks down for very small z . In this range the major contribution to the integral over \mathbf{r}_1 in Eq. (12) comes from small $|\mathbf{r}_1 - \mathbf{r}|$. For such \mathbf{r}_1 , and assuming that $\xi(\mathbf{r})$ is smooth, one can expand $\xi(\mathbf{r}_1) - \xi(\mathbf{r}) \approx |\nabla \xi(\mathbf{r})| \cdot |\mathbf{r}_1 - \mathbf{r}| \cdot \cos \phi$ where ϕ is the angle between $\nabla \xi(\mathbf{r})$ and $\mathbf{r}_1 - \mathbf{r}$. One can then integrate over $|\mathbf{r}_1 - \mathbf{r}|$ for a given ϕ and z_1 , then over z_1 , and ultimately over ϕ . For $z \rightarrow 0$, to the leading order in $1/z$ the result reads

$$V^{\text{pol}}(\mathbf{r}, z) \approx -\frac{\Lambda}{2\pi z} \int_{-\pi/2}^{\pi/2} d\phi \frac{\pi - 2 \arctan y(\mathbf{r}, \phi)}{y(\mathbf{r}, \phi)}, \\ y(\mathbf{r}, \phi) = [|\nabla \xi(\mathbf{r})| \cos \phi]^{-1} \quad (15)$$

For small $|\nabla \xi(\mathbf{r})|$, this expression is $\propto |\nabla \xi(\mathbf{r})|^2$, to the leading order in $|\nabla \xi(\mathbf{r})|$. It then coincides with the asymptotic form of H_i^{el} for small z , where the major contribution to H_i^{el} comes from $V_{\mathbf{q}_1, \mathbf{q}_2}^{(2)}(z)$. Numerically, approximating Eq. (15) by the term $\propto |\nabla \xi(\mathbf{r})|^2$ works well in a broad range of $|\nabla \xi(\mathbf{r})|$; even for $|\nabla \xi(\mathbf{r})| = 0.7$ the difference with the full expression (15) is $< 10\%$, and it decreases fast with the decreasing $|\nabla \xi(\mathbf{r})|$.

The assumption of the smoothness of $\xi(\mathbf{r})$ used in Eq. (15) requires that the root mean square displacement $\langle \xi^2(\mathbf{r}) \rangle^{1/2}$ largely exceed the typical length on which $\xi(\mathbf{r})$ changes. If we limit the ripplon wave numbers to $q_c = 10^8 \text{ cm}^{-1}$, for the $T = 0$ fluctuations we have $q_c \langle \xi^2(\mathbf{r}) \rangle_{T=0}^{1/2} \sim 1.5$, cf. Fig. 1(c) of the main text. This shows that Eq. (15) is a good approximation for small $|\nabla \xi(\mathbf{r})|$, whereas for $|\nabla \xi(\mathbf{r})| \gtrsim 1$ in the expansion of $\xi(\mathbf{r}_1) - \xi(\mathbf{r})$ in Eq. (12) one should take into account higher-order terms in $\mathbf{r}_1 - \mathbf{r}$. They lead to $V^{\text{pol}}(\mathbf{r}, z)$ increasing even slower than z^{-1} with the decreasing z , for very small z .

From Eq. (15), the region of small z does not contribute appreciably to the matrix elements of $V^{\text{pol}}(\mathbf{r}, z)$ on the wave functions $\psi_n(z)$, which are $\propto z$ for small z . In the whole region $|\nabla \xi(\mathbf{r})| \leq 1$ the integral of $z^2 V^{\text{pol}}(\mathbf{r}, z)$ over the range $z \lesssim \langle \xi^2(\mathbf{r}) \rangle_{T=0}^{1/2} \sim 10^{-8}$ cm gives an extremely small contribution to the level shift, $\lesssim R \langle \xi^2(\mathbf{r}) \rangle_{T=0} / r_B^2 \sim 10^{-3} R$ (we keep only the $T = 0$ terms in this estimate, since only such terms are essential for large ripplon wave numbers). At the same time, for not too small z the coupling energy (12) is nonsingular and can be expanded in $\xi(\mathbf{r})$. This justifies using Eqs. (13) and (14) to describe the electrostatic electron-riplon coupling.

The direct two-riplon coupling $\propto V_{\mathbf{q}_1, \mathbf{q}_2}^{(2)}(z)$ leads to a shift of the energy levels already in the first order of the perturbation theory. From Eq. (13), for an n th level the shift is

$$\Delta \tilde{E}_n^{(2)} = \sum_{\mathbf{q}} \langle n | V_{\mathbf{q}, -\mathbf{q}}^{(2)}(z) | n \rangle | Q_{\mathbf{q}} |^2 (2\bar{n}_{\mathbf{q}} + 1).$$

$$\Delta E_{n\mathbf{p}}^{\text{pot}} = \hbar \sum_{\mathbf{q}, \alpha} \mathcal{N}_{q\alpha} \sum_{n'} (E_n - E_{n'} - \Delta_{\mathbf{p}, \mathbf{q}, \alpha})^{-1} \left[\hbar \left| \langle n' | V_{\mathbf{q}}^{(1)}(z) | n \rangle \right|^2 - 2(E_n - E_{n'}) \text{Im} \langle n | p_z | n' \rangle \langle n' | V_{\mathbf{q}}^{(1)}(z) | n \rangle \right], \quad (16)$$

where $\mathcal{N}_{q\alpha} = |Q_{\mathbf{q}}|^2 [\bar{n}_{\mathbf{q}} + (1 + \alpha)/2] / \hbar^2$, cf. the main text; $\Delta_{\mathbf{p}, \mathbf{q}, \alpha}$ is defined in the main text below Eq. (5). The level shift (16) should be added to the purely kinematic shift given by Eq. (7) of the main text to describe the full level shift due to the electron-riplon coupling. Note that the term with $n' = n$ gives the polaronic shift due to virtual processes within the same subband of motion normal to the surface, see [8, 11, 12]. The term quadratic in the pressing field E_{\perp} , which gives the major contribution to this shift for large E_{\perp} [12], is independent of the subband number n and drops out from the expression for the frequency of inter-subband transitions, which is of the central interest for this paper.

A numerical calculation shows that, for typical pressing fields $E_{\perp} \lesssim 300$ V/cm, the $T = 0$ level shift described by Eq. (16) is much smaller than the $T = 0$ kinematic shift discussed in the main text. For $E_{\perp} = 106$ V/cm (the field used in the experiment discussed in the main text), the $T = 0$ term in the sum (16) for $n = 1$ and $q \gtrsim 10^7$ cm $^{-1}$ is an order of magnitude smaller than the corresponding term in Eq. (7) of the main text. The $T = 0$ shift given by Eq. (16) is a part of the small deviation from the simple model of noninteracting electrons above the flat helium surface. Such deviation has not been measured in the experiment, and it is not easy to measure. This paper shows that the deviation is small without using adjustable parameters or extra approximations.

The terms linear in $\xi_{\mathbf{q}}$ give a shift when taken to the second order. This shift is determined by the matrix elements of the sum of the kinematic interaction $\hat{H}_i^{(1)}$ [Eq. (3) of the main text] and the linear in $\xi_{\mathbf{q}}$ terms in Eq. (13). To calculate the sum over the intermediate electron states, one can use the Bethe trick, Eq. (6) of the main text. One can then use the relation $i[p_z, V_{\mathbf{q}}^{(1)}(z)] = \hbar V_{\mathbf{q}, -\mathbf{q}}^{(2)}(z)$, which follows from Eq. (14), to show that the shift $\Delta \tilde{E}_n^{(2)}$ cancels out (in the calculation one should also use the completeness condition $\sum_{n'} \langle n | \hat{A} | n' \rangle \langle n' | \hat{B} | n \rangle = \langle n | \hat{A} \hat{B} | n \rangle$ that holds for any operators \hat{A}, \hat{B}). The full expression for the level shift due to the electrostatic electron-riplon coupling, which also includes the cross term from the electrostatic and kinematic coupling, is

III. TWO-RIPPLON SCATTERING

As indicated in the main text, the two-riplon coupling can provide an important contribution to inelastic electron scattering. This is a consequence of the possibility to scatter into ripples with large wave numbers q, q' while keeping the total ripplon momentum $\hbar(\mathbf{q} + \mathbf{q}')$ small, of the order of the electron thermal momentum or the reciprocal quantum localization length in a magnetic field multiplied by \hbar . The scattering rate is determined by the transition matrix elements calculated for the same total energy and the same total momentum of the electron-riplon system in the initial and final states. These matrix elements (the vertex, in terms of the diagrams) are given by the direct two-riplon coupling in the first order and the single-riplon coupling in the second order of the perturbation theory.

If only the direct two-riplon coupling was kept in the analysis of inelastic scattering, this would lead to a very high scattering rate. For example, the rate of transitions from the bottom of the first excited subband ($n = 2, \mathbf{p} = 0$) to the lowest subband ($n = 1$) due to the kinematic coupling $\hat{H}_i^{(2)}$ [Eq. (3) of the main text] would be $\gtrsim 10^8$ s $^{-1}$. This is orders of magnitude higher than in the existing experimental data. However, as in the case of the electron energy shift, the major part of the direct coupling is compensated by the linear in $\xi(\mathbf{r})$ coupling $\hat{H}_i^{(1)}$. To find this compensation, one can use again the Bethe trick.

We consider an electron transition from the initial

state $|n_i, \mathbf{p}_i, \{n(\mathbf{q})\}\rangle$ to the final state $|n_f, \mathbf{p}_f, \{n'(\mathbf{q})\}\rangle$, where $|\{n(\mathbf{q})\}\rangle$ is the ripplon wave function in the occupation number representation. To the first order in

$\hat{H}_i^{(2)}$ and to the second order in $\hat{H}_i^{(1)}$, the matrix element $\mathcal{M}_{if}^{\text{kin}}(\mathbf{q}_1, \mathbf{q}_2)$ of the kinematic coupling, which describes a two-riplon transition with emission or absorption of ripples with wave vectors \mathbf{q}_1 and \mathbf{q}_2 , has the form

$$\begin{aligned} \mathcal{M}_{if}^{\text{kin}}(\mathbf{q}_1, \mathbf{q}_2) = g_{\alpha\beta} \hbar^{-2} Q_{q_1} Q_{q_2} & \left[\langle n_f | p_z^2 | n_i \rangle (E_{n_i} - E_{n_f}) - \sum_{n'} \langle n_f | p_z | n' \rangle \langle n' | p_z | n_i \rangle (E_{n_i} - E_{n'}) \right. \\ & \left. \times (L_{n_i n'}^{\alpha_1 \alpha_2}(\mathbf{q}_1, \mathbf{q}_2) + L_{n_i n'}^{\alpha_2 \alpha_1}(\mathbf{q}_2, \mathbf{q}_1)) \right], \quad L_{n_i n'}^{\alpha_1 \alpha_2}(\mathbf{q}_1, \mathbf{q}_2) = \Delta_{\mathbf{p}_i + \hbar \mathbf{q}_1, \mathbf{q}_2, \alpha_2} / (E_{n_i} - E_{n'} - \Delta_{\mathbf{p}_i, \mathbf{q}_1, \alpha_1}) \end{aligned} \quad (17)$$

Here, the subscripts $\alpha_{1,2}$ indicate whether the transition is accompanied by ripplon emission ($\alpha_1 = \alpha_2 = 1$), absorption ($\alpha_1 = \alpha_2 = -1$), or scattering ($\alpha_1 = -\alpha_2 = \pm 1$). Factor $g_{\alpha_1 \alpha_2} \equiv g_{\alpha_1 \alpha_2}(\mathbf{q}_1, \mathbf{q}_2)$ is determined by the initial ripplon occupation numbers, $g_{\alpha_1, \alpha_2}(\mathbf{q}_1, \mathbf{q}_2) = \{[n(-\alpha_1 \mathbf{q}_1) + (1 + \alpha_1)/2][n(-\alpha_2 \mathbf{q}_2) + (1 + \alpha_2)/2]\}^{1/2}$. In the final ripplon state $|\{n'(\mathbf{q})\}\rangle$ the occupation numbers of ripples with the wave vectors $-\alpha_1 \mathbf{q}_1$ and $-\alpha_2 \mathbf{q}_2$ are changed by α_1 and α_2 , respectively, compared to the state $|\{n(\mathbf{q})\}\rangle$. In Eq. (17) we took into account that the final and initial energy of the electron-riplon system is the same as is also the total in-plane momentum,

$$\mathbf{p}_f = \mathbf{p}_i + \hbar(\mathbf{q}_1 + \mathbf{q}_2).$$

One can similarly calculate the contribution of the electrostatic electron-riplon coupling to the matrix element of two-riplon scattering. An important cancellation of the terms with large ripplon momenta occurs in this case, too. To the first order in the direct electrostatic two-riplon coupling and to the second order in the one-riplon electrostatic coupling and the cross-term with the one-riplon kinematic coupling, using Eq. (14) we obtain for the matrix element of the same transition as in Eq. (17) the expression

$$\begin{aligned} \mathcal{M}_{if}^{\text{pot}}(\mathbf{q}_1, \mathbf{q}_2) = g_{\alpha_1 \alpha_2} Q_{q_1} Q_{q_2} & \left\{ \left\langle n_f \left| \Lambda \left[\frac{2}{z^3} - \frac{(\mathbf{q}_1 + \mathbf{q}_2)^2}{z} K_2(|\mathbf{q}_1 + \mathbf{q}_2|z) \right] - i \left[\frac{E_{n_f} - E_{n_i}}{\hbar \Delta_{\mathbf{p}_i, \mathbf{q}_1, \alpha_1}} p_z V_{\mathbf{q}_1}^{(1)} + (\mathbf{q}_1 \rightleftharpoons \mathbf{q}_2) \right] \right| n_i \right\rangle \right. \\ & \left. + \left[\frac{\langle n_f | V_{\mathbf{q}_2}^{(1)} | n' \rangle \langle n' | V_{\mathbf{q}_1}^{(1)} - (i/\hbar)(E_{n_i} - E_{n'}) p_z | n_i \rangle}{E_{n_i} - E_{n'} - \Delta_{\mathbf{p}_i, \mathbf{q}_1, \alpha_1}} - i \frac{(E_{n_i} - E_{n'}) \Delta_{\mathbf{p}_i + \hbar \mathbf{q}_1, \mathbf{q}_2, \alpha_2} \langle n_f | p_z | n' \rangle \langle n' | V_{\mathbf{q}_1}^{(1)} | n_i \rangle}{\hbar \Delta_{\mathbf{p}_i, \mathbf{q}_1, \alpha_1} (E_{n_i} - E_{n'} - \Delta_{\mathbf{p}_i, \mathbf{q}_1, \alpha_1})} + (\mathbf{q}_1 \rightleftharpoons \mathbf{q}_2) \right] \right\}. \end{aligned} \quad (18)$$

Here $V_{\mathbf{q}}^{(1)}$ is a shorthand for $V_{\mathbf{q}}^{(1)}(z)$ and “ $+(\mathbf{q}_1 \rightleftharpoons \mathbf{q}_2)$ ” means adding the same expression with the interchanged $\{\mathbf{q}_1, \alpha_1\}$ and $\{\mathbf{q}_2, \alpha_2\}$; function g_{α_1, α_2} is defined below

Eq. (17). Numerical calculations of the relaxation rate based on Eqs. (17) and (18) are beyond the scope of the present paper.

- [1] C. C. Grimes, T. R. Brown, M. L. Burns, and C. L. Zipfel, Phys. Rev. B **13**, 140 (1976).
- [2] F. Stern, Phys. Rev. B **17**, 5009 (1978).
- [3] M. V. Rama Krishna and K. B. Whaley, Phys. Rev. B **38**, 11839 (1988).
- [4] E. Cheng, M. W. Cole, and M. H. Cohen, Phys. Rev. B **50**, 1136 (1994).
- [5] M. H. Degani, G. A. Farias, and F. M. Peeters, Phys. Rev. B **72**, 125408 (2005).
- [6] E. Collin, W. Bailey, P. Fozooni, P. G. Frayne, P. Glasson, K. Harrabi, M. J. Lea, and G. Papageorgiou, Phys. Rev. Lett. **89**, 245301 (2002).

- [7] E. Collin, W. Bailey, P. Fozooni, P. G. Frayne, P. Glasson, K. Harrabi, and M. J. Lea, ArXiv e-prints (2017), 1707.02119.
- [8] M. W. Cole, Phys. Rev. B **2**, 4239 (1970).
- [9] V. Shikin and Y. Monarkha, J. Low Temp. Phys. **16**, 193 (1974).
- [10] M. I. Dykman, P. Platzman, and P. Seddighrad, Phys. Rev. B **67**, 155402 (2003).
- [11] V. B. Shikin, JETP **33**, 387 (1971).
- [12] S. A. Jackson and P. M. Platzman, Phys. Rev. B **24**, 499 (1981).